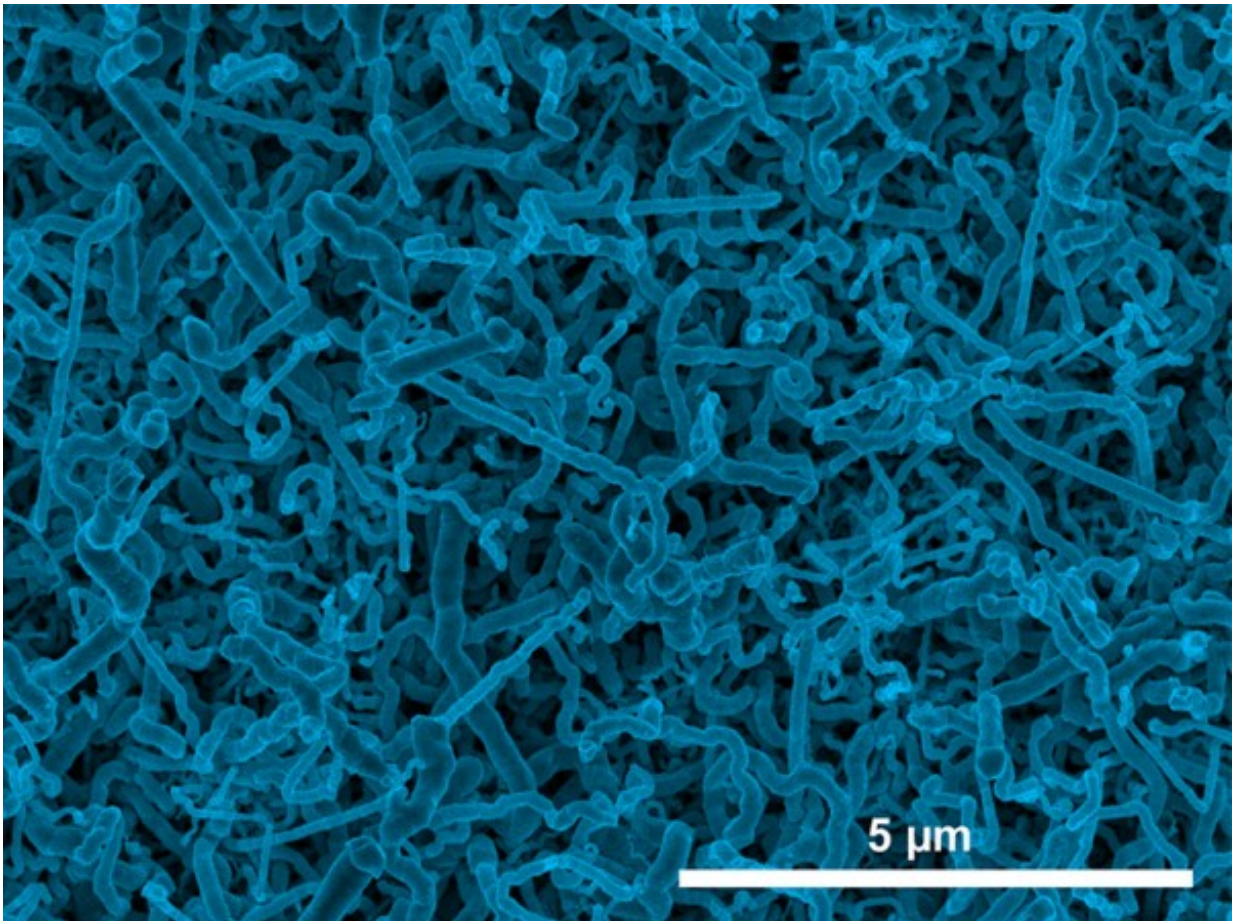


Highly conductive germanium nanowires made by a simple, one-step process

April 27 2015



Scanning electron micrograph image of germanium nanowires electrodeposited onto an indium tin oxide electrode from aqueous solution. Credit: Jay Switzer

For the first time, germanium nanowires have been deposited on indium tin oxide substrate by a simple, one-step process called electrodeposition.

The germanium nanowires produced by this method have superior electronic properties compared to silicon and can be used as high-capacity [anode material](#) for [lithium-ion batteries](#), but the nanowires were previously too expensive and difficult to produce. This process may resolve the cost issue to advance this battery technology.

Germanium is a semiconductor that has superior [electronic properties](#) compared to silicon, and is being considered as a replacement for silicon in semiconductor technology. It is also an attractive anode material for lithium-ion batteries because it has a large theoretical charge-discharge capacity compared to graphite and high lithium ion diffusivity at room temperature compared to silicon.

The large volume changes associated with charge-discharge processes require anodes be made of high-surface-area nanostructures of germanium. A lack of inexpensive and simple methods to produce germanium nanostructures has so far limited their use in battery electrode applications. Now, researchers at the Missouri University of Science and Technology have shown for the first time that germanium nanowires can be deposited by a simple, one-step process called electrodeposition that could provide a low cost route to fabricate these anodes. The nanowires were grown on an indium [tin oxide](#) substrate.

An electrochemical reduction produces tiny indium nanoparticles on the [indium tin oxide](#) surface, which act as sites for the nucleation and crystallization of germanium nanowires. The nanowire diameter can be controlled by the solution temperature: wires grown at room temperature have an average diameter of 35 nanometers, whereas those grown at 95°C have an average diameter of 100 nanometers. The [germanium](#) nanowires produced by this method are highly conductive, because they

contain a small amount of indium impurity (~0.2 atomic percent), making them ideal for lithium-ion battery applications.

More information: "Electrodeposited germanium nanowires." *ACS Nano* 9, 9524–9530 (2014). [[DOI: 10.1021/nm503784d](https://doi.org/10.1021/nm503784d)]

Provided by US Department of Energy

Citation: Highly conductive germanium nanowires made by a simple, one-step process (2015, April 27) retrieved 18 April 2024 from <https://phys.org/news/2015-04-highly-germanium-nanowires-simple-one-step.html>

This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.